Introduction to SAWAVE

A 3D Based Surface Acoustic Wave (SAWAVE) Device Simulator





SAWAVE FV Data Structure

- Unstructured Finite Volume (FV) mesh allows unparalleled flexibility in 3D structure definition.
- Efficient 3D stress solver with GPU acceleration (optional).
- Convenient 3D GUI allows use of GDSII mask layout format.
- Compatible with all existing Crosslight device simulators.
- Efficient wave solver uses coupled mode theory, incorporating results from 3D stress solver.
- Convenient graphic output using CrosslightView (OpenGL-based).



SAWAVE Input Data

- 3D metal and piezoelectrical crystal geometry and mesh definition for single or multiple periods.
- SAW device segments along wave propagation direction (number of periods of interdigital finger, or IDF), with or without acoustic grating. Open or short circuit IDF.
- Stiffness matrix parameters (Young's modulus, Poisson's ratio and shear modulus), piezoelectric parameter tensors and mass densities conveniently collected in material libraries for commonly-used SAW materials.
- Crystal cut rigorously described by miller indices.
- > Wave reflectivity at both ends of SAW device.
- Frequency range and number of frequency data points required.



SAWAVE Output Data

- All 3D displacement vectors and stress components excited by input AC bias (such as Sxx, Sxy, Syy, Szz, etc.), obtained rigorously from the FV stress solver.
- SAW lateral mode averaged Rayleigh wave vector as a function of position along the propagation direction; used to extract coupling coefficient kappa
- SAW lateral mode averaged piezo stress source distribution used to perform Green's function analysis for the whole multiple period device.
- Rayleigh wave amplitude distribution in the whole device.
- Y and S parameters, reflection and transmission coefficients versus frequency.



SAWAVE Easy to Use GUI

- Mature and integrated UI.
- Automatic input lookup and assistance.
- Large number of examples.
- Large material database.
- Automated series of simulation and design of experiment (DOE).



Basic equations

$$-\omega^2 \rho u_i = \frac{\partial}{\partial x_j} \left[\left(c_{ijkl} \frac{\partial u_k}{\partial x_l} \right) + e_{ijk} \frac{\partial \Phi}{\partial x_k} \right]$$

$$D_{i} = e_{ijk} \frac{\partial u_{j}}{\partial x_{k}} - \mathcal{E}_{ij} \frac{\partial \Phi}{\partial x_{j}}$$

Plus the usual Poisson's equation and the current continuity equations, for both DC and AC analysis (ref: Chen and Haus, IEEE Trans Sonic and Ultrasonic, vol. SU-32, p395, 1985)

Elastic stiffness tensor
$$C_{ijkl}$$

$$c_{\alpha\beta} = \begin{pmatrix} c_{11} & c_{12} & c_{13} & c_{14} & c_{15} & c_{16} \\ c_{21} & c_{22} & c_{23} & c_{24} & c_{25} & c_{26} \\ c_{31} & c_{32} & c_{33} & c_{34} & c_{35} & c_{36} \\ c_{41} & c_{42} & c_{43} & c_{44} & c_{45} & c_{46} \\ c_{51} & c_{52} & c_{53} & c_{54} & c_{55} & c_{56} \\ c_{61} & c_{62} & c_{63} & c_{64} & c_{65} & c_{66} \end{pmatrix}$$

36 independent elastic constants due to symmetry

A pair of unordered indices (i, j) can give 6 independent values

$$(11) \leftrightarrow 1 \qquad (22) \leftrightarrow 2 \qquad (33) \leftrightarrow 3 (23) = (32) \leftrightarrow 4 \qquad (31) = (13) \leftrightarrow 5 \qquad (12) = (21) \leftrightarrow 6$$

Effect of Crystal Symmetry on c_{ijkl}



Ref. Daniel Royer, Eugène Dieulesaint, "Elastic Waves in solids I Free and Guided Propagation", Springer

	_		_	_	_	_	_	-	_	-						-
Material	Clas	Stiffness (10 ¹⁰ N/m ²)												Mass density (kg/m ³		
Isotropic, cubic system			<i>c</i> ₁₁				C ₁₂				C ₄₄				ρ	1
Aluminium (Al) Gallium arsenide (GaAs)	m 3m 43m		10.73 11.88				6.08 5.38				2.83 5.94				2 702 5 307	
(Y ₃ Al ₅ O ₁₂), YAG	m 3m		33.2				11.07				11.50				4 550	
(Y ₃ Fe ₅ O ₁₂), YIG Bismuth and germanium oxide	m 3m		26.9				10.77				7.64				5 170	
(Bi ₁₂ GeO ₂₀)	23		12.8					;	3.05		2.55				9 230	
Gold (Au)	m 3m		19.25					10	6.30		4.24				19 300	I
Platinum (Pt)	m 3m		34.7					2	5.1		7.65				21 400	I
	isotropic		7.85						1.61		3.12				2 203	1
Silicon (Si)	m 3m m 2m		1	.56			6.39			7.95				2 329	1	
		"		.24			20.44				16.0	.06		19 260	ļ	
Hexagonal system			<i>c</i> ₁₁		c	C 12		C ₁₃		4	c 33		C 44			
Beryllium (Be)	6/ <i>mmm</i>		29.23		2.67		7	1.4		3	33.64		16.25		1 848	Ī
Ceramic P21-4	6 <i>mm</i>		13.9		7.8		.	7.4			11.5		2.56		7 500	l
Cadmium sulphide (CdS)	6 <i>mm</i>		20.9		5.20		51	4.62		2	0.36		4.25		5 676	I
Titanium (Ti)	6/mmm		16.24		9.20		51	6.90			9.30		4.67		4 624	I
	G mmm		10.24		Ľ	0.20		0.00		L."	10.07		4.07		4 300	l
Tetragonal system			C ₁₁		C 12	С	13	c	33	C 44	C	66	C	16		
Indium (In)	4/ mm	m	4.53	Γ	4.00	4.	.15	4.	51	0.65	5 1.2		1 0		7 280	Ī
Lead molybdate (PbMoO ₄)	4/m	- li	10.92		6.83	5.	.28	8 9.1		2.67	37 3.3		7 1.36		6 950	l
Calcium molybdate (CaMoO ₄)	4/ <i>m</i>		14.5		6.6	4.	.46	16 12.0		3.69	9 4.5		1.3	3	4 255	
Paratellurite (1eO ₂)	422		5.6	L	5.1	2.2		10.6		2.65	5 6.6		0	21	6 000	l
Barium titanate (BaTiO)	4/mmm 4/mm		27.3		17.6	14	4.9	48.4		12.5	19	4		21	4 250	l
bandin thanate (Dario ₃)	4000		21.5		17.9		5.2	Ľ	5.5	0.43		.3			6 020	L
Trigonal system			c 11		C 12		с,	3	C ₃	3	C 44		C 14			
Alumina (Al ₂ O ₃)	Зm	Τ	49.7		16.3		11.	.1 49		8 14.7		- 2.35		35	3 986	ſ
Lithium niobate (LiNbO3)	3m		20.3		5.3		7.	.5 24		5	6.0		0.9		4 700	l
Lithium tantalate (LiTaO ₃)	3m		23.3		4.7		8.	.0 27.		5	9.4		-1.1		7 450	
α -Quartz (SiO ₂)	32		8.67		0.70		1.	19 10.		72 5.79		9 -	9 -1.79		2 648	l
renunum (re)	32		3.27		0.86		2.	49 /		22	3.1	2	1.24		6 250	
Orthorhombic system		<i>c</i> ₁	C1	2	C ₁₃	c	22	C 2	3 0	33	C 44	c 5	5	C 66	ρ	ſ
α-iodic acid (HIO ₃)	222	3.0	1 1.6	51	1.11	5.	.80	0.8	0 4	29	1.69	2.0	6 1	.58	4 640	ſ
(Ba ₂ NaNb ₅ O ₁₅)	2mm	23.	9.10.	.4	5.0	2	4.7	5.2	2 1	3.5	6.5	6.6		7.6	5 300	

Elastic stiffness constants and mass densities for various crystals, organized according to crystal class.

Ref. Daniel Royer, Eugène Dieulesaint, "Elastic Waves in solids I Free and Guided Propagation", Springer



$$Piezoelectric tensor e_{ijk}$$

$$e_{i\alpha} = \begin{vmatrix} e_{11} & e_{12} & e_{13} & e_{14} & e_{15} & e_{16} \\ e_{21} & e_{22} & e_{23} & e_{24} & e_{25} & e_{26} \\ e_{31} & e_{32} & e_{33} & e_{34} & e_{35} & e_{36} \end{vmatrix}$$

Independent piezoelectric constants reduced from 27 to 18 due to symmetry

NovaTl

Effect of Crystal Symmetry on *e*_{*ijk*}



Components of the elastic, piezoelectric and dielectric tensors, organized according to symmetry class,

- : zero component,
- -o: equal and opposite components,
- • : non-zero component,
- equal components,
- \times : component equal to $(c_{11} c_{12})/2$.

Ref. Daniel Royer, Eugène Dieulesaint, "Elastic Waves in solids I Free and Guided Propagation", Springer

NovaTCAD

Material	Class	Piezoelectric constant									Permittivit				
			(C/m ²)								(10 ⁻¹¹ F/m				
Cubic system			e ₁₄									ε ^s			
Gallium arsenide (GaAs)	43 <i>m</i>	- 0.16							T	9.73					
oxide (Bi ₁₂ GeO ₂₀)	23		0.99									2			
Hexagonal system		e ₁₅			e ₃₁				e ₃₃	ε	1	ϵ^S_{33}			
Ceramic PZT-4	6mm	12.7		Γ	- 5.2				15.1	65	0	560			
Zinc oxide (ZnO)	6mm	- 0.59			- 0.61				1.14	73		7.83			
Cadmium sulphide (CdS)	6 <i>mm</i>	-0	.21	- 0.24					0.44	7.9	9	8.44			
Tetragonal system		e ₁₄		e ₁	e ₁₅ e ₃₁		Τ	e ₃₃		,	ϵ^{S}_{33}				
Paratellurite (TeO ₂) Barium titanate (BaTiO ₃)	422 4mm	0.22 0	22		0 21.3		0 - 2.6		0 3.64	1 74	20 14	22 97			
Trigonal system		e ₁₁	e ₁₄	e ₁₅		e ₂₂		<i>e</i> ₃ .	e ₃₃	ε <mark>s</mark>	1	ϵ_{33}^S			
Lithium niobate (LiNbO ₃) Lithium tantalate (LiTaO ₃) α Quartz (SiO ₂)	3 <i>m</i> 3 <i>m</i> 32	0 0 0.171	0	20.02	3.7 2.6 0	2.5 1.6 0		0.2 ≅0 0	1.3 1.9 0	38. 36.	9 3	25.7 38.1			
_			0.041							3.9	2	4.10			
Orthorhombic system		e ₁₅	<i>e</i> ₂ ,	4	e	31		e ₃₂	e ₃₃	ϵ_{11}^{S}	ε ^{\$} 22	ε ε ₃₃			
Barium sodium niobate (Ba ₂ NaNb ₅ O ₁₅)	2mm	2.8	3.4	ł	- (0.4	-	0.3	4.3	196	201	28			

Piezoelectric and dielectric constants for crystals, classified by crystal system

Ref. Daniel Royer, Eugène Dieulesaint, "Elastic Waves in solids I Free and Guided Propagation", Springer



Stress equations



 $\sigma_{xx} = C_{11}\frac{\partial u}{\partial x} + C_{12}\frac{\partial v}{\partial v} + C_{13}\frac{\partial w}{\partial z} + C_{14}\frac{\partial w}{\partial v} + C_{14}\frac{\partial v}{\partial z} + C_{15}\frac{\partial w}{\partial x} + C_{15}\frac{\partial u}{\partial z} + C_{16}\frac{\partial v}{\partial x} + C_{16}\frac{\partial v}{\partial v}$ $\sigma_{yy} = C_{21}\frac{\partial u}{\partial x} + C_{22}\frac{\partial v}{\partial y} + C_{23}\frac{\partial w}{\partial z} + C_{24}\frac{\partial w}{\partial y} + C_{24}\frac{\partial v}{\partial z} + C_{25}\frac{\partial w}{\partial x} + C_{25}\frac{\partial u}{\partial z} + C_{26}\frac{\partial v}{\partial x} + C_{26}\frac{\partial u}{\partial y}$ $\sigma_{zz} = C_{31}\frac{\partial u}{\partial x} + C_{32}\frac{\partial v}{\partial v} + C_{33}\frac{\partial w}{\partial z} + C_{34}\frac{\partial w}{\partial v} + C_{34}\frac{\partial v}{\partial z} + C_{35}\frac{\partial w}{\partial x} + C_{35}\frac{\partial u}{\partial z} + C_{36}\frac{\partial v}{\partial x} + C_{36}\frac{\partial u}{\partial v}$ $\sigma_{xy} = \sigma_{yx} = C_{61}\frac{\partial u}{\partial x} + C_{62}\frac{\partial v}{\partial y} + C_{63}\frac{\partial w}{\partial z} + C_{64}\frac{\partial w}{\partial y} + C_{64}\frac{\partial v}{\partial z} + C_{65}\frac{\partial w}{\partial x} + C_{65}\frac{\partial u}{\partial z} + C_{66}\frac{\partial v}{\partial x} + C_{66}\frac{\partial u}{\partial y}$ $\sigma_{yz} = \sigma_{zy} = C_{41} \frac{\partial u}{\partial x} + C_{42} \frac{\partial v}{\partial v} + C_{43} \frac{\partial w}{\partial z} + C_{44} \frac{\partial w}{\partial v} + C_{44} \frac{\partial v}{\partial z} + C_{45} \frac{\partial w}{\partial x} + C_{45} \frac{\partial u}{\partial z} + C_{46} \frac{\partial v}{\partial x} + C_{46} \frac{\partial u}{\partial v}$ $\sigma_{zx} = \sigma_{xz} = C_{51}\frac{\partial u}{\partial x} + C_{52}\frac{\partial v}{\partial v} + C_{53}\frac{\partial w}{\partial z} + C_{54}\frac{\partial w}{\partial v} + C_{54}\frac{\partial v}{\partial z} + C_{55}\frac{\partial w}{\partial x} + C_{55}\frac{\partial u}{\partial z} + C_{56}\frac{\partial v}{\partial x} + C_{56}\frac{\partial v}{\partial v} + C_{56}$



Simulated Structure







All stress components are computed, but Stress_xy and Stress_yy are used to determined lateral profile of the propagating wave





Wave amplitude of SAW from Green's function method at near the Bragg frequency.

NovaTCAD



Induced displacement current in IDF per period.





Induced displacement current in IDF per period near Bragg frequency.





Rayleigh wave vector versus distance. Coupling coefficient kappa is extracted for coupled mode theory.

NovaTCAD



stress source averaged over lateral wave profile, used as source term in Green's function analysis.

NovaTEAD



Trend comparison with experiment



Transfer characteristics from 4 IDF of a long SAW device (Quartz/Cu).

4 pair insertion loss measurement on LiNbO3/unknown-metal (Ref: IEEE Trans. Sonics and Ultrasonics, vol. 24, p. 147, 1977)



Summary

- For the first time, a specialized 3D SAW device simulator is available commercially.
- High frequency analysis of the whole SAW device can be performed efficiently based on combined 3D stress solver and Rayleigh wave coupled mode solver.
- Advance features include crystal orientation, metal mass loading, open and short circuit effects and all stress component analysis.
- Commonly measured quantities such as S-parameters can be conveniently obtained.



Crosslight Customer Locations





A Canadian company with **20** years of history The world's **first** commercial TCAD for laser diode

